

# ZXTP19060CG

## 60V PNP medium transistor in SOT223

### Summary

$BV_{CEO} > -60V$

$BV_{ECO} > -7V$

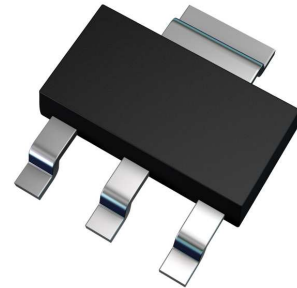
$I_{C(cont)} = 5A$

$V_{CE(sat)} < -80mV @ -1A$

$R_{CE(sat)} = 50m\Omega$

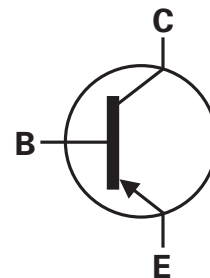
$P_D = 3.0W$

Complementary part number ZXTN19060CG



### Description

Packaged in the SOT223 outline this new low saturation PNP transistor offers extremely low on state losses making it ideal for use in DC-DC circuits and various driving and power management functions.

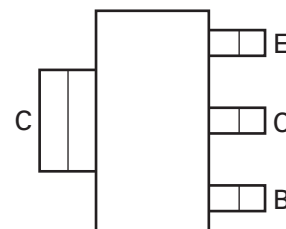


### Features

- High Gain
- Low saturation voltage
- High peak current
- 7V reverse blocking voltage

### Applications

- High side driver
- Motor drive
- Load disconnect switch



Pinout - top view

### Ordering information

| Device        | Reel size (inches) | Tape width (mm) | Quantity per reel |
|---------------|--------------------|-----------------|-------------------|
| ZXTP19060CGTA | 7                  | 12              | 1000              |

### Device marking

ZXTP19060C

## Absolute maximum ratings

| Parameter   | Symbol         | Limit      | Unit  |
|---|----------------|------------|-------|
| Collector-Base voltage                              | $V_{CBO}$      | -60        | V     |
| Collector-Emitter voltage                           | $V_{CEO}$      | -60        | V     |
| Emitter-Collector voltage (reverse blocking)        | $V_{ECX}$      | -7         | V     |
| Emitter-Base voltage                                | $V_{EBO}$      | -7         | V     |
| Continuous Collector current <sup>(c)</sup>         | $I_C$          | -5         | A     |
| Base current  | $I_B$          | -1         | A     |
| Peak pulse current                                  | $I_{CM}$       | -7         | A     |
| Power dissipation at $T_A = 25^\circ\text{C}^{(a)}$ | $P_D$          | 1.2        | W     |
| Linear derating factor                              |                | 9.6        | mW/°C |
| Power dissipation at $T_A = 25^\circ\text{C}^{(b)}$ | $P_D$          | 1.6        | W     |
| Linear derating factor                              |                | 12.8       | mW/°C |
| Power dissipation at $T_A = 25^\circ\text{C}^{(c)}$ | $P_D$          | 3.0        | W     |
| Linear derating factor                              |                | 24         | mW/°C |
| Power dissipation at $T_A = 25^\circ\text{C}^{(d)}$ | $P_D$          | 5.3        | W     |
| Linear derating factor                              |                | 42         | mW/°C |
| Power dissipation at $T_C = 25^\circ\text{C}^{(e)}$ | $P_D$          | 10.2       | W     |
| Linear derating factor                              |                | 81         | mW/°C |
| Operating and storage temperature range             | $T_j, T_{stg}$ | -55 to 150 | °C    |

## Thermal resistance

| Parameter                          | Symbol          | Limit | Unit |
|------------------------------------|-----------------|-------|------|
| Junction to ambient <sup>(a)</sup> | $R_{\theta JA}$ | 104   | °C/W |
| Junction to ambient <sup>(b)</sup> | $R_{\theta JA}$ | 78    | °C/W |
| Junction to ambient <sup>(c)</sup> | $R_{\theta JA}$ | 42    | °C/W |
| Junction to ambient <sup>(d)</sup> | $R_{\theta JA}$ | 23.5  | °C/W |
| Junction to case <sup>(e)</sup>    | $R_{\theta JC}$ | 12.3  | °C/W |

### NOTES:

(a) For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

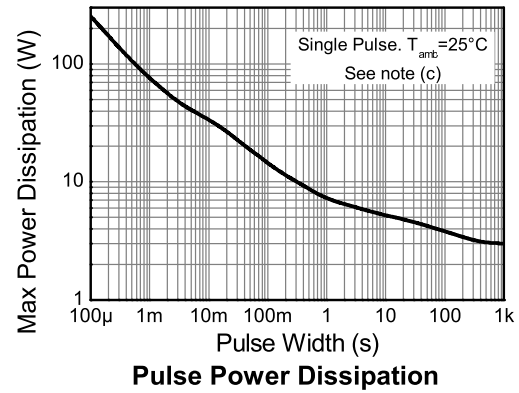
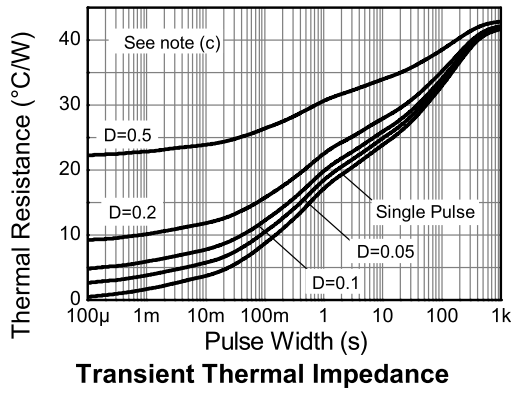
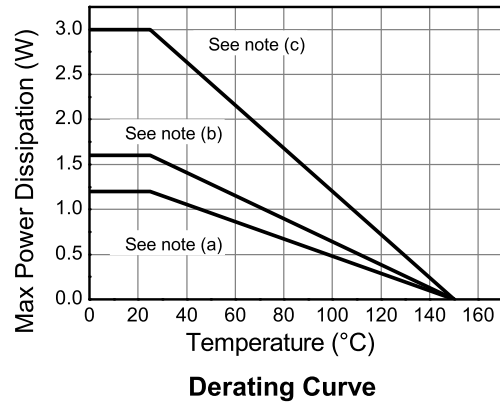
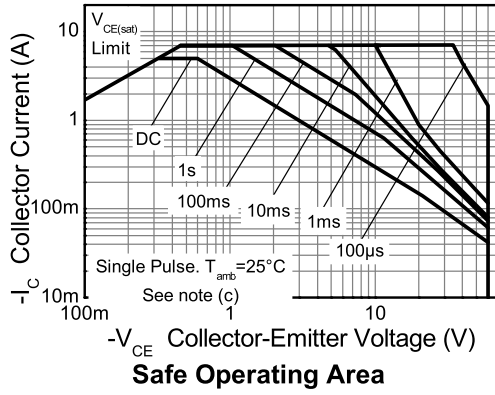
(b) Mounted on 25mm x 25mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

(c) Mounted on 50mm x 50mm x 0.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions.

(d) As (c) above measured at  $t < 5$  seconds.

(e) Junction to case (collector tab). Typical

## Thermal characteristics



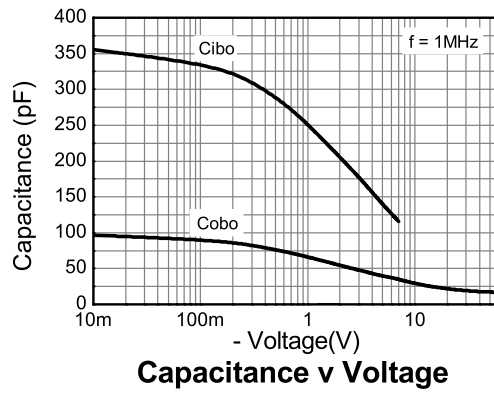
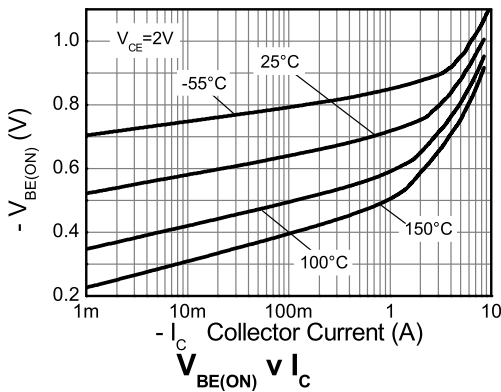
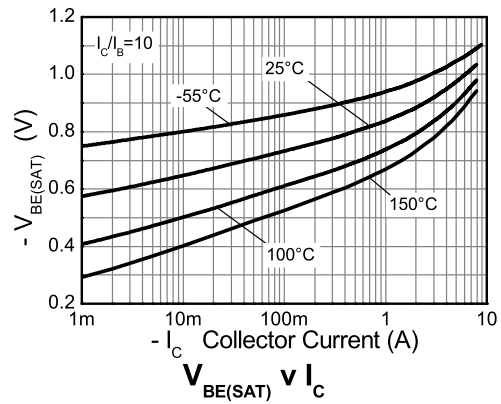
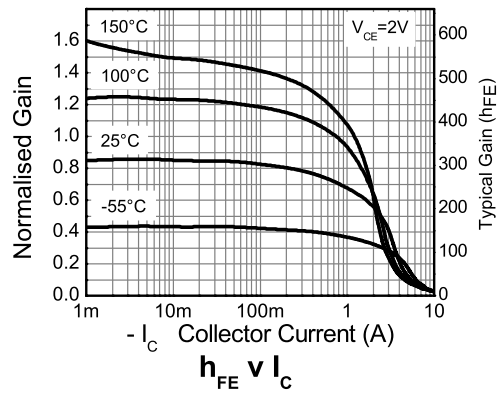
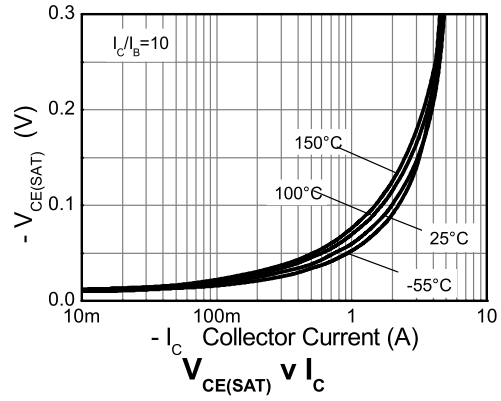
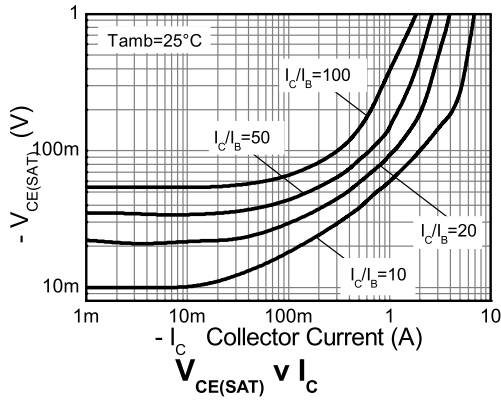
## Electrical characteristics (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated)

| Parameter  | Symbol        | Min.             | Typ.  | Max.  | Unit                             | Conditions   |
|--|---------------|------------------|---|---|----------------------------------|--|
| Collector-Base breakdown voltage                       | $BV_{CBO}$    | -60              | -110  |   | V                                | $I_C = -100\mu\text{A}$  |
| Collector-Emitter breakdown voltage                    | $BV_{CEO}$    | -260             | -90   |   | V                                | $I_C = -10\text{mA}^{(*)}$   |
| Emitter-Collector breakdown voltage (reverse blocking) | $BV_{ECX}$    | -7               | -8.4  |   | V                                | $I_E = -100\mu\text{A}$ , $R_{BC} < 1\text{k}\Omega$ or $0.25\text{V} > V_{BC} > -0.25\text{V}$  |
| Emitter-Collector breakdown voltage (reverse blocking) | $BV_{ECO}$    | -7               | -8.8  |   | V                                | $I_E = -100\mu\text{A}$  |
| Emitter-Base breakdown voltage                         | $BV_{EBO}$    | -7               | -8.4  |   | V                                | $I_E = -100\mu\text{A}$  |
| Collector-Base cut-off current                         | $I_{CBO}$     |                  | <1  | -50<br>-0.5                                 | nA<br>$\mu\text{A}$              | $V_{CB} = -60\text{V}$<br>$V_{CB} = -60\text{V}$ , $T_{amb} = 100^{\circ}\text{C}$   |
| Emitter cut-off current                                | $I_{EBO}$     |                  | <1  | -50   | nA                               | $V_{EB} = -5.6\text{V}$  |
| Collector-Emitter saturation voltage                   | $V_{CE(sat)}$ |                  | -62<br>-145<br>-500<br>-105<br>-145<br>-300 | -80<br>-205<br>-750<br>-165<br>-200<br>-500 | mV<br>mV<br>mV<br>mV<br>mV<br>mV | $I_C = -1\text{A}$ , $I_B = -100\text{mA}^{(*)}$<br>$I_C = -1\text{A}$ , $I_B = -20\text{mA}^{(*)}$<br>$I_C = -2\text{A}$ , $I_B = -40\text{mA}^{(*)}$<br>$I_C = -2\text{A}$ , $I_B = -200\text{mA}^{(*)}$<br>$I_C = -3\text{A}$ , $I_B = -300\text{mA}^{(*)}$<br>$I_C = -5\text{A}$ , $I_B = -500\text{mA}^{(*)}$ |
| Base-Emitter saturation voltage                        | $V_{BE(sat)}$ |                  | -975  | -1050                                       | mV                               | $I_C = -5\text{A}$ , $I_B = -500\text{mA}^{(*)}$   |
| Base-Emitter turn-on voltage                           | $V_{BE(on)}$  |                  | -890  | -1000                                       | mV                               | $I_C = -5\text{A}$ , $V_{CE} = -2\text{V}^{(*)}$   |
| Static forward current transfer ratio                  | $h_{FE}$      | 200<br>160<br>20 | 330<br>260<br>40                            | 500   |                                  | $I_C = -100\text{mA}$ , $V_{CE} = -2\text{V}^{(*)}$<br>$I_C = -1\text{A}$ , $V_{CE} = -2\text{V}^{(*)}$<br>$I_C = -5\text{A}$ , $V_{CE} = -2\text{V}^{(*)}$  |
| Transition frequency                                   | $f_T$         |                  | 180   |   | MHz                              | $I_C = -50\text{mA}$ , $V_{CE} = -10\text{V}$<br>$f = 50\text{MHz}$  |
| Input capacitance                                      | $C_{ibo}$     |                  | 280   | 400   | pF                               | $V_{EB} = -0.5\text{V}$ , $f = 1\text{MHz}^{(*)}$  |
| Output capacitance                                     | $C_{obo}$     |                  | 29.5  | 40  | pF                               | $V_{CB} = -10\text{V}$ , $f = 1\text{MHz}^{(*)}$   |
| Delay time   | $t_d$         |                  | 24.3  |   | ns                               | $I_C = -500\text{mA}$ , $V_{CC} = -10\text{V}$ ,<br>$I_{B1} = -I_{B2} = -50\text{mA}$  |
| Rise time  | $t_r$         |                  | 13.2  |   | ns                               |  |
| Storage time   | $t_s$         |                  | 456   |   | ns                               |  |
| Fall time  | $t_f$         |                  | 68.2  |   | ns                               |  |

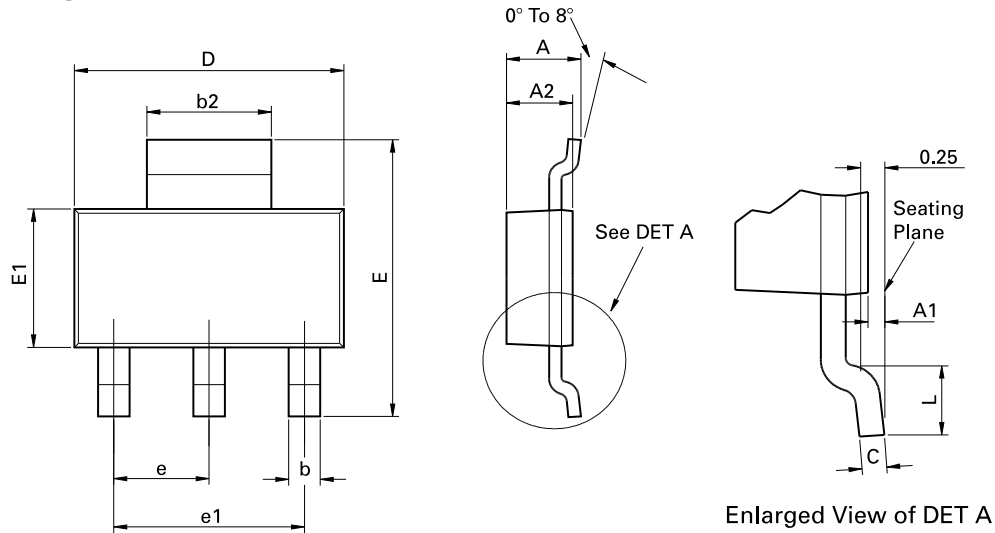
### NOTES:

(\*) Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ ; duty cycle  $\leq 2\%$ .

## Typical characteristics



## Package outline - SOT223



Conforms to JEDEC TO-261 AA Issue B

| Dim. | Millimeters |      | Inches |        | Dim. | Millimeters |      | Inches     |       |
|------|-------------|------|--------|--------|------|-------------|------|------------|-------|
|      | Min.        | Max. | Min.   | Max.   |      | Min.        | Max. | Min.       | Max.  |
| A    | -           | 1.80 | -      | 0.071  | D    | 6.30        | 6.70 | 0.248      | 0.264 |
| A1   | 0.02        | 0.10 | 0.0008 | 0.004  | e    | 2.30 BSC    |      | 0.0905 BSC |       |
| A2   | 1.55        | 1.65 | 0.0610 | 0.0649 | e1   | 4.60 BSC    |      | 0.181 BSC  |       |
| b    | 0.66        | 0.84 | 0.026  | 0.033  | E    | 6.70        | 7.30 | 0.264      | 0.287 |
| b2   | 2.90        | 3.10 | 0.114  | 0.122  | E1   | 3.30        | 3.70 | 0.130      | 0.146 |
| C    | 0.23        | 0.33 | 0.009  | 0.013  | L    | 0.90        | -    | 0.355      | -     |

**Note:** Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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